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APPLICATION NO. FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/885,792	06/20/2001	Basanth Jagannathan	FIS920000402US1	4506	
	590 04/07/2003				
WHITHAM, CURTIS & CHRISTOFFERSON, P.C.			EXAMINER		
11491 SUNSE SUITE 340	T HILLS ROAD	LATTIN, CHRISTOPHER W			
RESTON, VA	20190		ART UNIT	PAPER NUMBER	
			2812		
			DATE MAILED: 04/07/2003		

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.		Αρμίicant(s)	
		09/885,792		JAGANNATHAN ET AL.	
	Office Action Summary	Examiner		Art Unit	
		Christopher W L	attin	2812	
riad for	- The MAILING DATE of this communication r Reply				S
THE M - Exten after S - If the - If NO - Failur - Any re earne	DRTENED STATUTORY PERIOD FOR REMAILING DATE OF THIS COMMUNICATION is of time may be available under the provisions of 37 CF SIX (6) MONTHS from the mailing date of this communication period for reply specified above is less than thirty (30) days, a period for reply is specified above, the maximum statutory per to reply within the set or extended period for reply will, by seply received by the Office later than three months after the new department. See 37 CFR 1.704(b).	R 1.136(a). In no event, how no event, how no event, how no event, how a reply within the statutory mineriod will apply and will expire	rever, may a reply be tin nimum of thirty (30) day SIX (6) MONTHS from	nely filed s will be considered timely. the mailing date of this commu D. (35 U.S.C. § 133).	inication.
atus 1)⊠	Responsive to communication(s) filed on	10 March 2003.			
2a)□	This action is FINAL 2b)	This action is non-	final.		
3)□ ispositi	Since this application is in condition for a closed in accordance with the practice ur ion of Claims	idel Ex parte Quayie	formal matters, p e, 1935 C.D. 11,	rosecution as to the n 453 O.G. 213.	nerits is
4)⊠	Claim(s) 1-16 is/are pending in the applic	ation.			
	4a) Of the above claim(s) 1-12 is/are without	drawn from considera	ation.		
5)	Claim(s) is/are allowed.				
6)🖂	Claim(s) <u>13-16</u> is/are rejected.				
7)[]	Claim(s) _ is/are objected to.				
8)	Claim(s) are subject to restriction a	and/or election requi	rement.		
Applicat	tion Papers				
9)[The specification is objected to by the Exa	aminer.		inor	
10)	The drawing(s) filed on is/are: a)	accepted or b) obje	ected to by the Ex	aminer.	
	mot request that any objection	n to the drawing(s) be I	neld in abeyance.	See 37 Cr 1. 1.05(a).	
11)	The proposed drawing correction filed on	is: a) 🔲 appro	oved b) algabb	Toved by the Examiner.	
	If approved, corrected drawings are required	d in reply to this Office	action.		
12)[The oath or declaration is objected to by t	he Examiner.			
Priority	under 35 U.S.C. §§ 119 and 120			· () (d) ~~ (f)	
13)[Acknowledgment is made of a claim for the	foreign priority under	35 U.S.C. § 119	(a)-(d) or (i).	
	a) ☐ All b) ☐ Some * c) ☐ None of:				
	1.☐ Certified copies of the priority doc	uments have been re	eceived.	er. N.	
	2. Certified copies of the priority doc	uments have been re	eceived in Applic	ation No	togo
	Copies of the certified copies of the application from the Internation See the attached detailed Office action for				lage
•	* See the attached detailed Office action to] Acknowledgment is made of a claim for d	omestic priority unde	er 35 U.S.C. § 11	9(e) (to a provisional	application)
14)	 Acknowledgment is made of a claim for u a) ☐ The translation of the foreign language 	age provisional appli	cation has been	received.	
15)[a) ☐ The translation of the foreign language. Acknowledgment is made of a claim for contents. 	domestic priority und	er 35 U.S.C. §§ 1	120 and/or 121.	
Attachm		A	☐ Interview Sumr	nary (PTO-413) Paper No(s	s) ·
	otice of References Cited (PTO-892) otice of Draftsperson's Patent Drawing Review (PTO- formation Disclosure Statement(s) (PTO-1449) Papel	948) 5; r No(s) 6;	Notice of Inform	nal Patent Application (PTC)-152)
		Office Action Summary		Part of I	aper No. 12

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 13, 14 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chantre et al. (U.S. Patent 6,177,717) in view of Racanelli (U.S. Patent 6,410,975, previously cited by applicant).

Chantre et al. teach a transistor that has a collector region 60, a SiGe base 81, an emitter stack overlying the collector region, said emitter stack including an emitter opening filled with T-shaped polysilicon 111, said T-shaped polysilicon overlying nitride regions 10 included in said stack, SiGe extrinsic base regions (see Figure 6) arranged on respective sides of said emitter stack, the extrinsic base regions aligned with the polysilicon layer 111, but not directly with the emitter opening contacts, and contacts, but fails to teach that the extrinsic base regions are *directly* aligned with the polysilicon layer. Racanelli teaches a similar bipolar device with extrinsic base regions directly aligned with the polysilicon emitter layer in order to minimize the separation distance between the intrinsic and extrinsic regions. See Racanelli column 2 lines 2-40. It would have been obvious to one skilled in the art at the time of the invention to align the extrinsic base regions directly to the emitter stack in the invention of Chantre et al. in

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order to minimize the separation distance between the intrinsic and extrinsic regions as taught by Racanelli.

Claims 13, 14 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chantre et al. (U.S. Patent 6,177,717) in view of Racanelli (U.S. Patent 6,410,975, previously cited by applicant) as applied supra and further in view of the admitted prior art.

Chantre et al. are applied supra and teach all of the limitations of the device and appear to illustrate a longer extrinsic base region and a shorter extrinsic base region. However, it is not clear if a contact is formed on the longer extrinsic base region. The admitted prior art relates a well-known transistor that has a base contact formed on the longer extrinsic base region to form an electrical connection. It therefore would have been obvious to one skilled in the art at the time of the invention to have an electrical contact formed on the longer extrinsic base region.

Response to Arguments

Applicant's arguments with respect to the limitation in claims 13-16 of direct alignment have been considered but are most in view of the new ground(s) of rejection.

Applicant's argument with respect to a SiGe base region is not found persuasive.

Applicant argues that Chantre et al. teach a multilayered SiGe base, while the presently claimed method is drawn to a single layer. The claims, which employ "comprising"

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language, are not so limited to a single layer. Chantre et al. do teach a SiGe base as required by the claims.

Applicant's argument with respect to a multilayered emitter including oxide, nitride and TEOS layers is not found persuasive. The claim language does not limit the device to these layers. The claims do recite an emitter stack including an emitter opening filled with T-shaped polysilicon, said T-shaped polysilicon overlying nitride regions included in said stack, which is taught by Chantre et al. in column 5, lines 62-65.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Christopher Lattin whose telephone number is (703) 305-3017. The examiner can normally be reached Monday through Friday from 8:00 A.M. to 5:00 P.M.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling, can be reached at (703) 308-3325. The fax number for this Group is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0956.

Form F. Niebling
Supervisory Patent Examiner
Technology Center 2800

CWL 4 April 3, 2003